

# MPF108

CASE 29-02, STYLE 5  
TO-92 (TO-226AA)

JFET  
VHF AMPLIFIER  
N-CHANNEL — DEPLETION

## MAXIMUM RATINGS

| Rating                                                                                 | Symbol    | Value       | Unit                       |
|----------------------------------------------------------------------------------------|-----------|-------------|----------------------------|
| Drain-Source Voltage                                                                   | $V_{DS}$  | 25          | Vdc                        |
| Drain-Gate Voltage                                                                     | $V_{DG}$  | 25          | Vdc                        |
| Gate-Source Voltage                                                                    | $V_{GS}$  | -25         | Vdc                        |
| Forward Gate Current                                                                   | $I_{GF}$  | 10          | mA <sub>dc</sub>           |
| Total Device Dissipation @ $T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | $P_D$     | 310<br>2.82 | mW<br>mW/ $^\circ\text{C}$ |
| Junction Temperature Range                                                             | $T_J$     | -65 to +135 | $^\circ\text{C}$           |
| Storage Temperature Range                                                              | $T_{stg}$ | -65 to +150 | $^\circ\text{C}$           |

Refer to 2N4416 for graphs.

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted.)

| Characteristic                                                                                                                                                                                                  | Symbol              | Min    | Max         | Unit                                   |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------|--------|-------------|----------------------------------------|
| <b>OFF CHARACTERISTICS</b>                                                                                                                                                                                      |                     |        |             |                                        |
| Gate-Source Breakdown Voltage ( $I_G = 10\text{ }\mu\text{A}_{dc}$ , $V_{DS} = 0$ )                                                                                                                             | $V_{(BR)GSS}$       | -25    | —           | Vdc                                    |
| Gate Reverse Current ( $V_{GS} = -15\text{ Vdc}$ , $V_{DS} = 0$ )<br>( $V_{GS} = -15\text{ Vdc}$ , $V_{DS} = 0$ , $T_A = 100^\circ\text{C}$ )                                                                   | $I_{GSS}$           | —      | 1.0<br>-1.0 | nA <sub>dc</sub><br>$\mu\text{A}_{dc}$ |
| Gate-Source Cutoff Voltage* ( $V_{DS} = 15\text{ Vdc}$ , $I_D = 10\text{ }\mu\text{A}_{dc}$ )                                                                                                                   | $V_{GS(off)}$ *     | 0.5    | 8.0         | Vdc                                    |
| <b>ON CHARACTERISTICS</b>                                                                                                                                                                                       |                     |        |             |                                        |
| Zero-Gate-Voltage Drain Current* ( $V_{DS} = 15\text{ Vdc}$ , $V_{GS} = 0$ )                                                                                                                                    | $I_{DSS}$ *         | 1.5    | 24          | mA <sub>dc</sub>                       |
| <b>SMALL-SIGNAL CHARACTERISTICS</b>                                                                                                                                                                             |                     |        |             |                                        |
| Forward Transfer Admittance ( $V_{DS} = 15\text{ Vdc}$ , $V_{GS} = 0$ , $f = 100\text{ MHz}$ )                                                                                                                  | $ y_{fs} $          | 1600   | —           | $\mu\text{mhos}$                       |
| Forward Transadmittance* ( $V_{DS} = 15\text{ Vdc}$ , $V_{GS} = 0$ , $f = 1.0\text{ kHz}$ )                                                                                                                     | $y_{fs}$ *          | 2000   | 7500        | $\mu\text{mhos}$                       |
| Input Admittance ( $V_{DS} = 15\text{ Vdc}$ , $V_{GS} = 0$ , $f = 100\text{ MHz}$ )                                                                                                                             | $\text{Re}(y_{is})$ | —      | 800         | $\mu\text{mhos}$                       |
| Output Admittance ( $V_{DS} = 15\text{ Vdc}$ , $V_{GS} = 0$ , $f = 1.0\text{ kHz}$ )                                                                                                                            | $ y_{os} $          | —      | 75          | $\mu\text{mhos}$                       |
| Output Conductance ( $V_{DS} = 15\text{ Vdc}$ , $V_{GS} = 0$ , $f = 100\text{ MHz}$ )                                                                                                                           | $\text{Re}(y_{os})$ | —      | 200         | $\mu\text{mhos}$                       |
| Input Capacitance ( $V_{DS} = 15\text{ Vdc}$ , $V_{GS} = 0$ , $f = 1.0\text{ MHz}$ )                                                                                                                            | $C_{iss}$           | —      | 6.5         | pF                                     |
| Reverse Transfer Capacitance ( $V_{DS} = 15\text{ Vdc}$ , $V_{GS} = 0$ , $f = 1.0\text{ MHz}$ )                                                                                                                 | $C_{rss}$           | —      | 2.5         | pF                                     |
| <b>FUNCTIONAL CHARACTERISTICS</b>                                                                                                                                                                               |                     |        |             |                                        |
| Noise Figure<br>( $V_{DS} = 15\text{ Vdc}$ , $V_{GS} = 0$ , $R_G = 1.0\text{ Megohm}$ , $f = 1.0\text{ kHz}$ )<br>( $V_{DS} = 15\text{ Vdc}$ , $V_{GS} = 0$ , $R_G = 1.0\text{ k ohm}$ , $f = 100\text{ MHz}$ ) | NF                  | —<br>— | 2.5<br>3.0  | dB                                     |

\*To characterize these devices to narrower limits, regarding  $I_{DSS}$ ,  $V_{GS(off)}$  and  $y_{fs}$ , the entire production lot is tested and divided into color-coded groups, with each color dot representing a relatively small range compared with the total min-max limit of the whole distribution. The color codes and their associated limits are given in the following table.

When packaged for shipment, the colors are randomly selected and no specific color distribution is implied or guaranteed.

| Color  | $I_{DS}$                                           | $V_{GS(off)}$            | $y_{fs}$                      |
|--------|----------------------------------------------------|--------------------------|-------------------------------|
| Orange | 1.5 mA <sub>dc</sub> Min, 3.0 mA <sub>dc</sub> Max | 0.5 Vdc Min, 5.0 Vdc Max | 2000 to 6500 $\mu\text{mhos}$ |
| Yellow | 2.5 mA <sub>dc</sub> Min, 5.0 mA <sub>dc</sub> Max | 0.5 Vdc Min, 5.0 Vdc Max | 2000 to 6500 $\mu\text{mhos}$ |
| Green  | 4.0 mA <sub>dc</sub> Min, 8.0 mA <sub>dc</sub> Max | 1.0 Vdc Min, 7.0 Vdc Max | 2500 to 7000 $\mu\text{mhos}$ |
| Blue   | 7.0 mA <sub>dc</sub> Min, 14 mA <sub>dc</sub> Max  | 1.0 Vdc Min, 7.0 Vdc Max | 2500 to 7000 $\mu\text{mhos}$ |
| Violet | 12 mA <sub>dc</sub> Min, 24 mA <sub>dc</sub> Max   | 2.0 Vdc Min, 8.0 Vdc Max | 3000 to 7500 $\mu\text{mhos}$ |